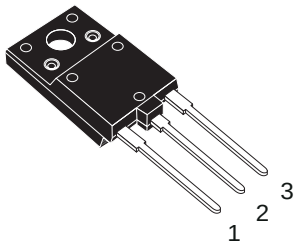
MD2009DFX

High voltage NPN Power transistor for standard definition CRT display

General features

- State-of-the-art technology:
  - diffused collector “enhanced generation”
- More stable performance versus operating temperature variation
- Low base drive requirement
- Tighter h_{FE} range at operating collector current
- Fully insulated power package U.L. compliant
- Integrated free wheeling diode
- In compliance with the 2002/93/EC European directive



ISOWATT218FX

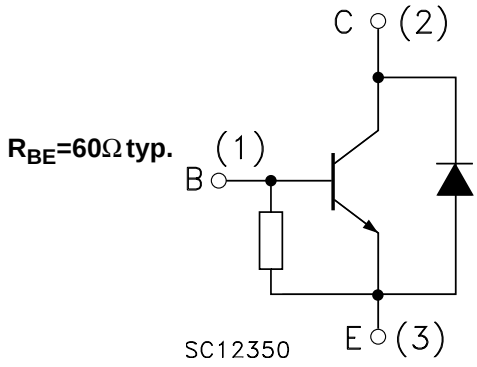
Applications

- Horizontal deflection output for TV

Description

The MD2009DFX is manufactured using Diffused Collector in Planar Technology adopting new and enhanced high voltage structure. The new MD product series show improved silicon efficiency bringing updated performance to the Horizontal Deflection stage.

Internal schematic diagram



Order codes

Part number	Marking	Package	Packaging
MD2009DFX	MD2009DFX	ISOWATT218FX	Tube

1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage (V_{BE} = 0)	1500	V
V_{CEO}	Collector-emitter voltage (I_B = 0)	700	V
V_{EBO}	Base-emitter voltage (I_C = 0)	7	V
I_C	Collector current	10	A
I_{CM}	Collector peak current (t_P < 5ms)	16	A
I_B	Base current	6	A
P_{TOT}	Total dissipation at T_c = 25°C	58	W
V_{isol}	Insulation withstand voltage (RMS) from all three leads to external heatsink	2500	V
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	

Table 2. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj\text{-}case}$	Thermal resistance junction-case max	2.15	°C/W

2 Electrical characteristics

(Tcase =25°C unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current (V_{BE} = 0)	V_{CE} = 1500V V_{CE} = 1500V, T_c= 125°C			0.2 2	mA mA
I_{EBO}	Emitter Cut-off Current (I_C = 0)	V_{EB} = 5V	40		120	mA
$V_{(BR)EBO}$	Emitter-base breakdown voltage (I_C = 0)	I_E = 700mA	10			V
$V_{CE(sat)}$(1)	Collector-emitter saturation voltage	I_C = 5.5A , I_B = 1.4A			2.8	V
$V_{BE(sat)}$(1)	Base-emitter saturation voltage	I_C = 5.5A , I_B = 1.4A			1.3	V
h_{FE}(1)	DC current gain	I_C = 1A, V_{CE} = 5V I_C = 5.5A, V_{CE} = 1V I_C = 5.5A , V_{CE} = 5V	 5	18 4.7	 7	
V_f	Diode forward voltage	I_F= 5.5 A			1.6	V
 t_s t_f	Inductive load Storage time Fall time	I_C = 5A, f_h = 16KHz $I_{B(on)}$ = 1.5A, $V_{BE(off)}$ = -2.7V $L_{BB(off)}$ = 6.2µH		 4.5 0.3	 6 0.6	 µs µs

1. Pulsed duration = 300 ms, duty cycle ≤1.5%.

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

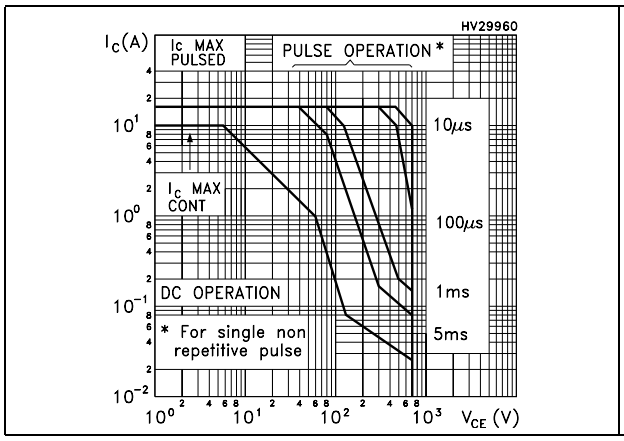


Figure 2. Derating curve

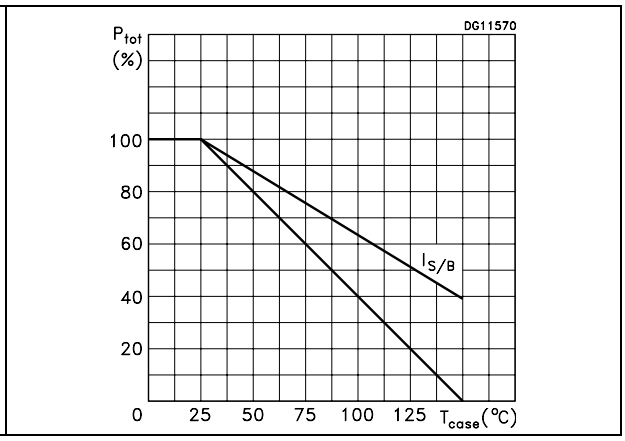


Figure 3. Output characterisics

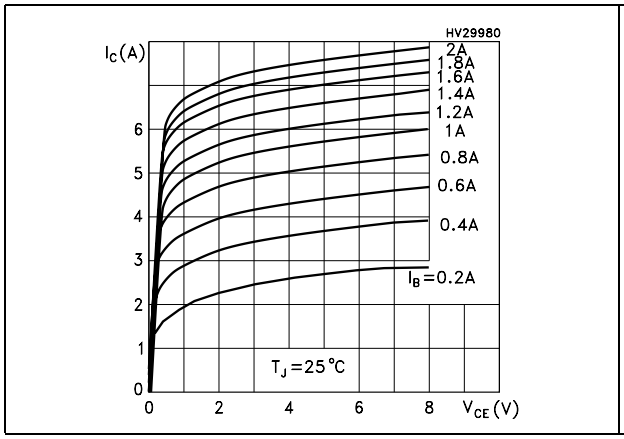


Figure 4. Reverse biased SOA

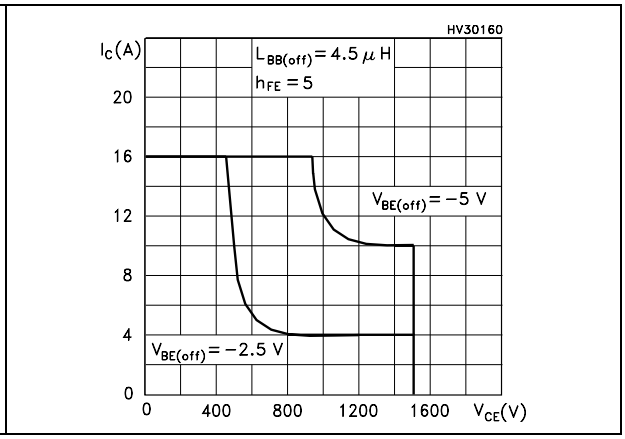


Figure 5. DC current gain

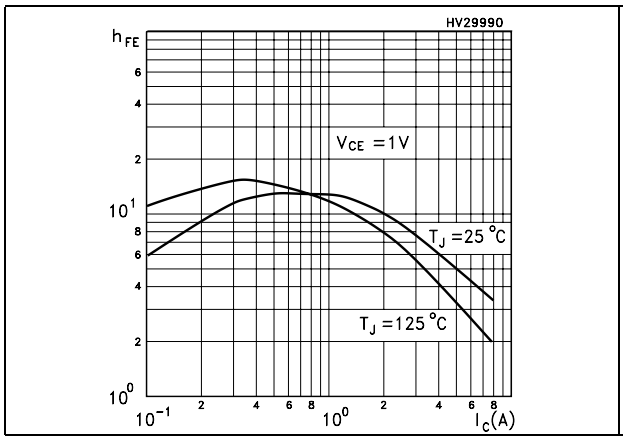


Figure 6. DC current gain

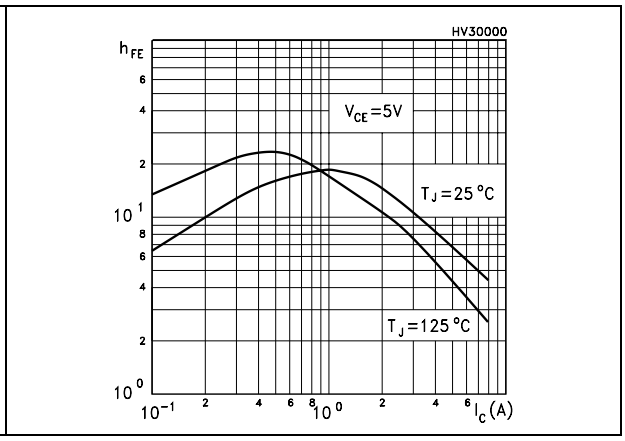


Figure 7. Collector-emitter saturation volatge

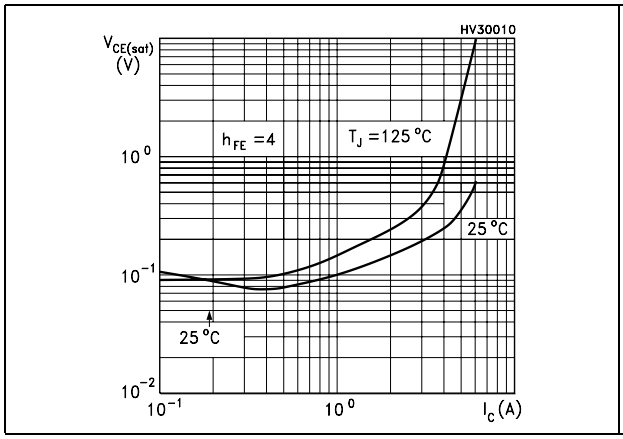


Figure 8. Base-emitter saturation voltage

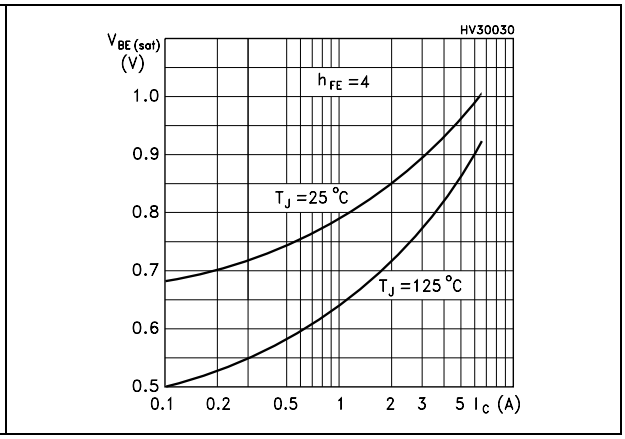


Figure 9. Power losses

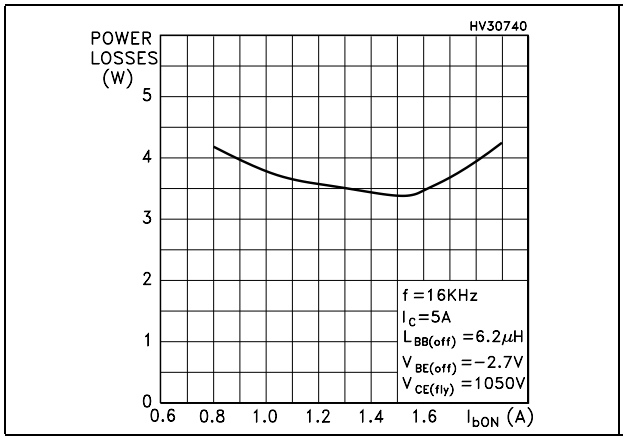
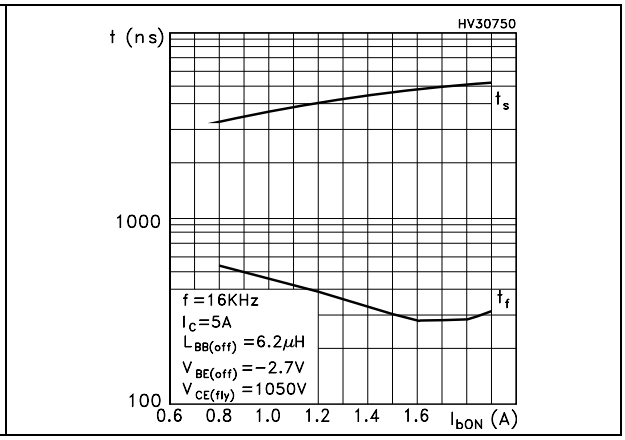


Figure 10. Inductive load switching time



3 Test circuits

Figure 11. Power losses and inductive load switching test circuit

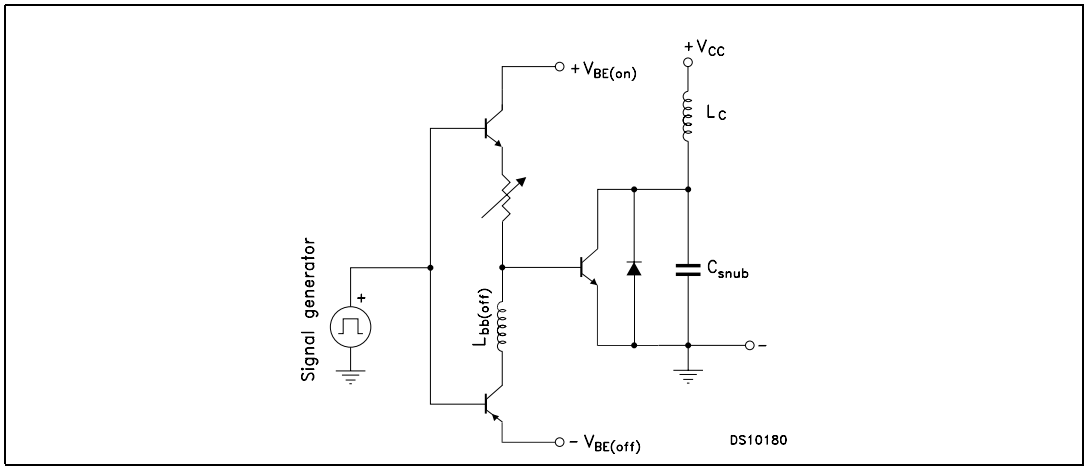
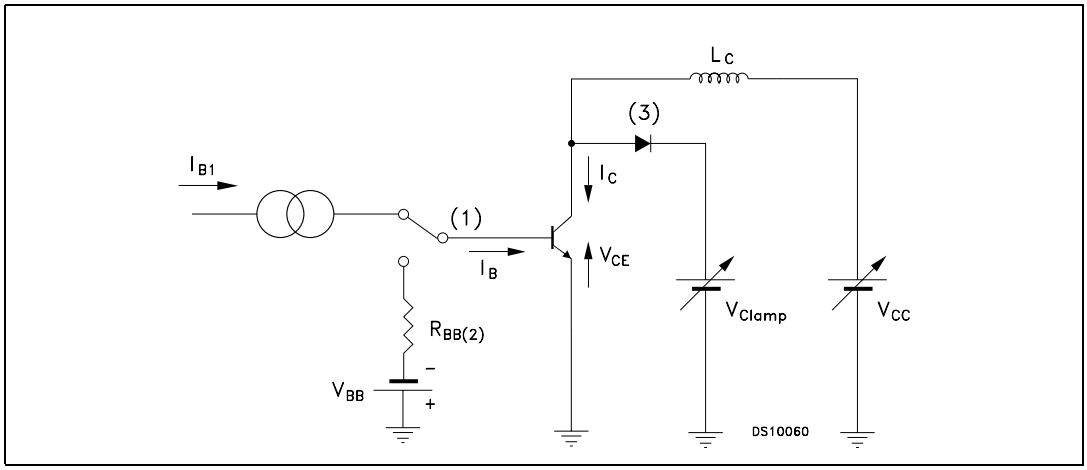


Figure 12. Reverse biased safe operating area test circuit

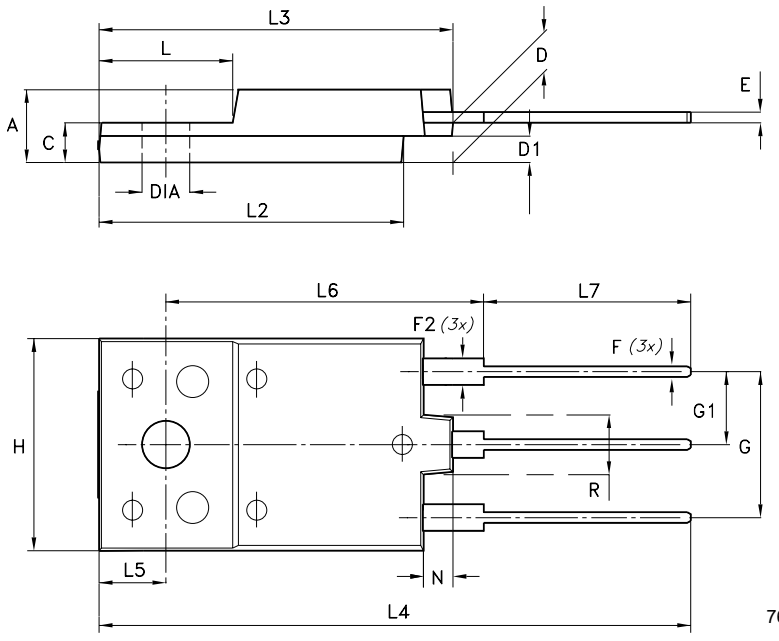


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

ISOWATT218FX MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	5.30		5.70
C	2.80		3.20
D	3.10		3.50
D1	1.80		2.20
E	0.80		1.10
F	0.65		0.95
F2	1.80		2.20
G	10.30		11.50
G1		5.45	
H	15.30		15.70
L	9		10.20
L2	22.80		23.20
L3	26.30		26.70
L4	43.20		44.40
L5	4.30		4.70
L6	24.30		24.70
L7	14.60		15
N	1.80		2.20
R	3.80		4.20
Dia	3.40		3.80



5 Revision history

Table 4. Revision history

Date	Revision	Changes
27-Feb-2006	1	First release
28-Mar-2006	2	New curves 9 and 10 inserted
22-May-2006	3	Values changed on *Table 1* and *Table 3*
20-Oct-2006	4	New hFE limits shown on *Table 3*

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST’s terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST’S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER’S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com